



Imaging individual Ba atoms in solid xenon for barium tagging in nEXO

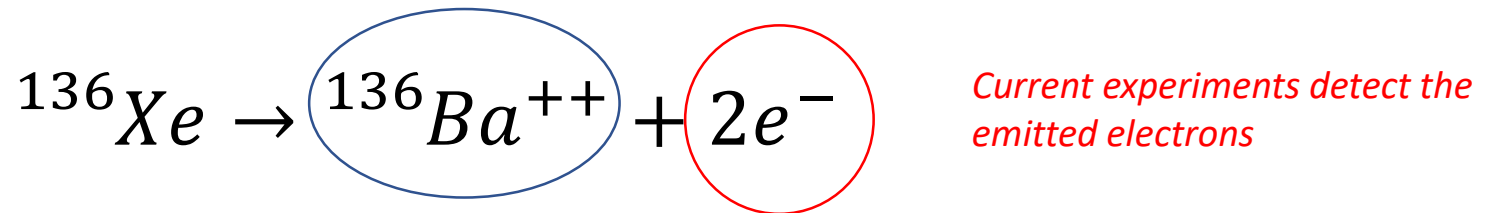
Bill Fairbank

Chris Chambers, David Fairbank, James Todd, Danielle Harris, Adam Craycraft, Alec Iverson

nEXO Collaboration

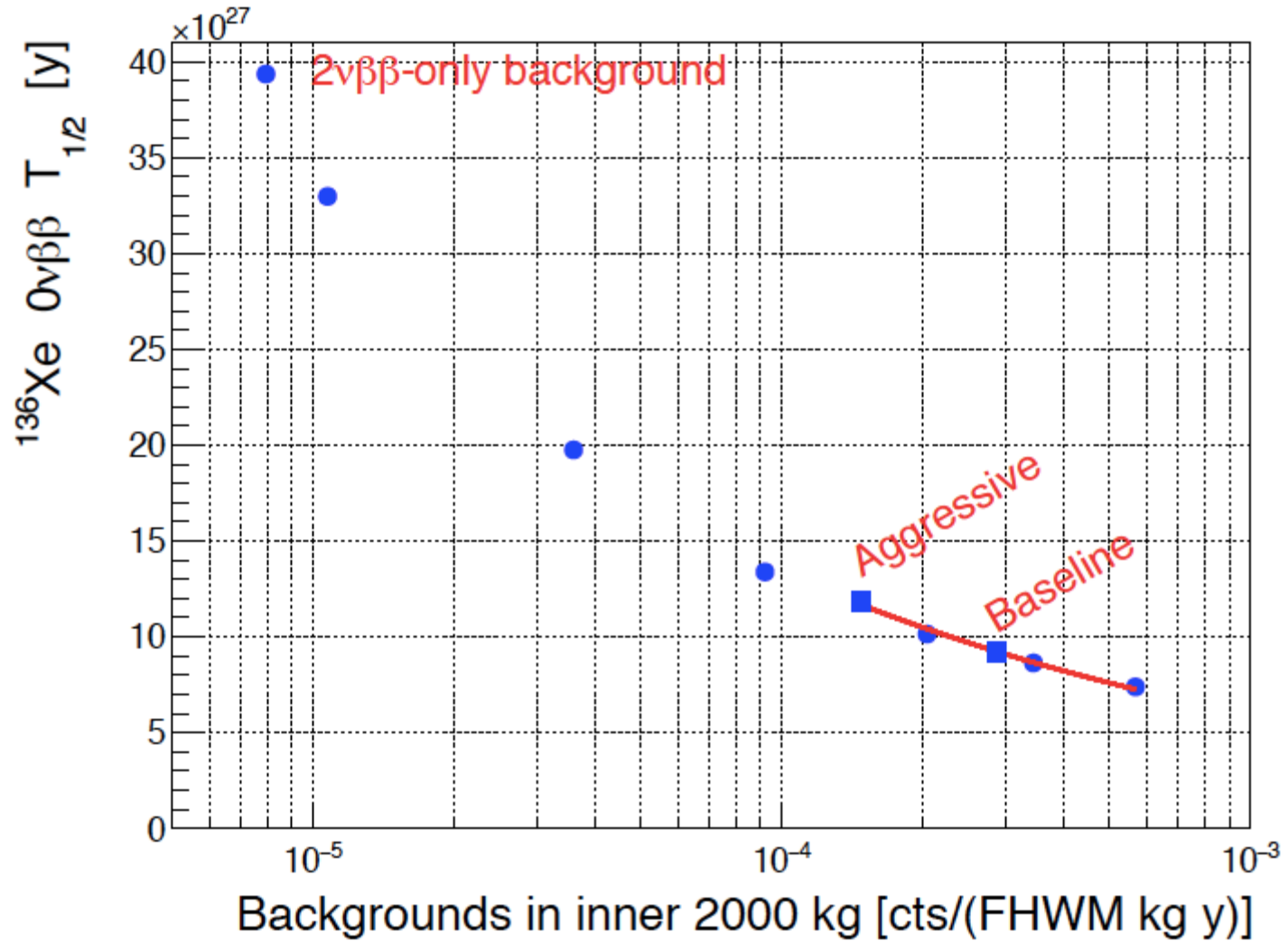


Extending the Sensitivity of Neutrinoless Double Beta Decay in the nEXO Detector



- **Ba Tagging: also detect the daughter ^{136}Ba ion or atom located at the decay position.**
- **Potential to eliminate all but $2\nu\beta\beta$ backgrounds**

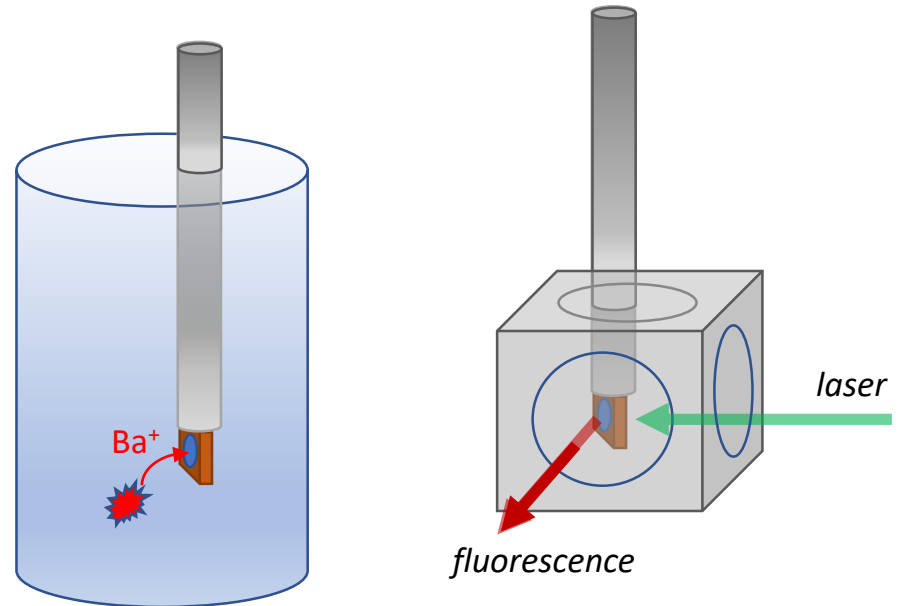
nEXO sensitivity vs. background



J. B. Albert et al., Phys. Rev. C 97, 065503 (2018)

Barium Tagging in Solid Xenon

- Locate the decay position with the TPC
- Insert a cryogenic probe and trap the Ba daughter in solid Xe
- Extract the probe and cool
- Tag the Ba daughter in the solid Xe via laser induced fluorescence



1 Ba \longrightarrow $\beta\beta$ decay
0 Ba \longrightarrow Not $\beta\beta$ decay

Probe in observation region - Use single Ba imaging technique we present in this work.

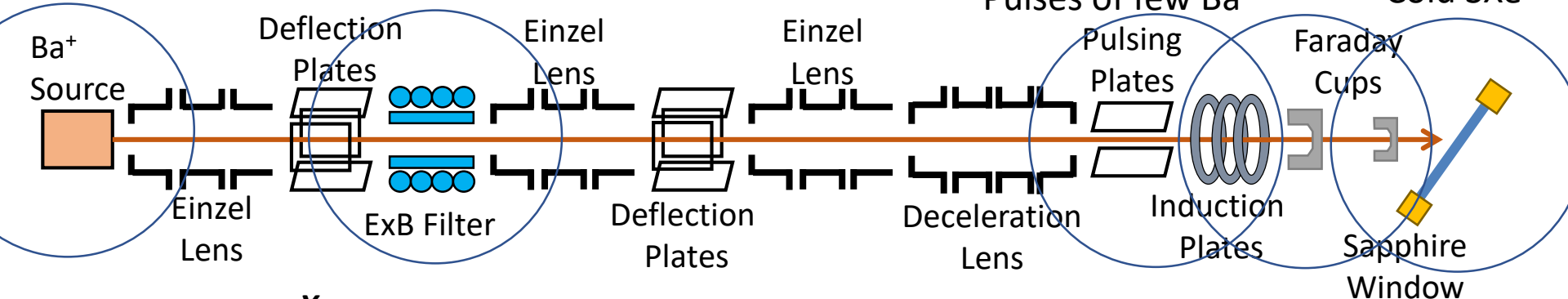
Requires counting of *single* Ba in solid Xe

Ba⁺ Ion Deposition System

Mass selection: just Ba⁺

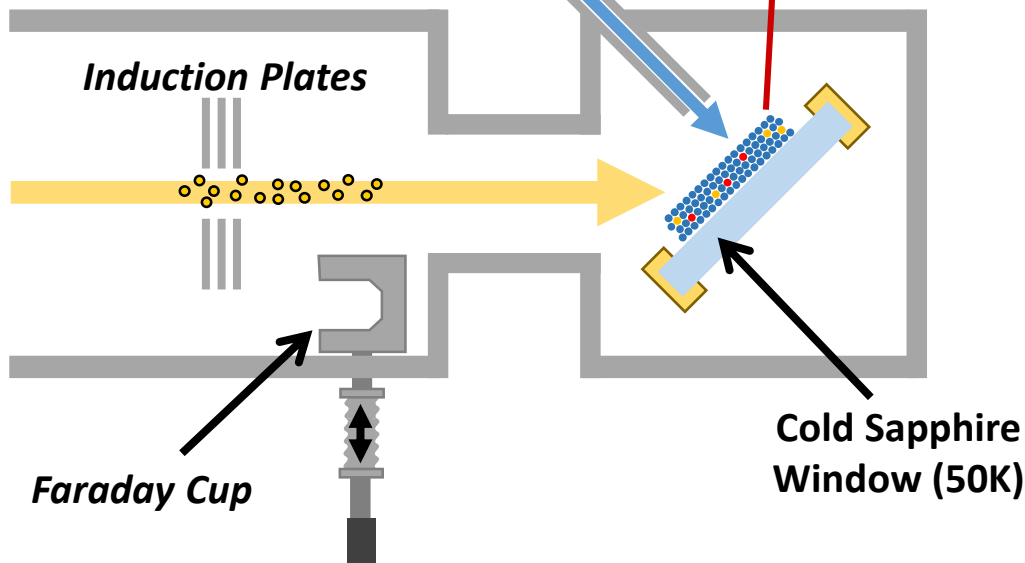
Measure # Ba⁺

Clean Ba⁺ source



Xe gas

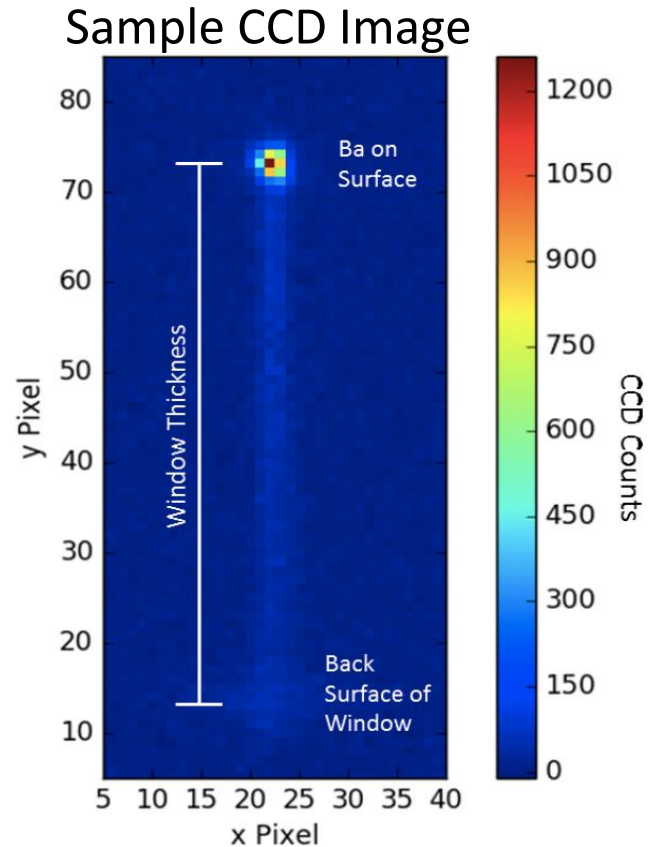
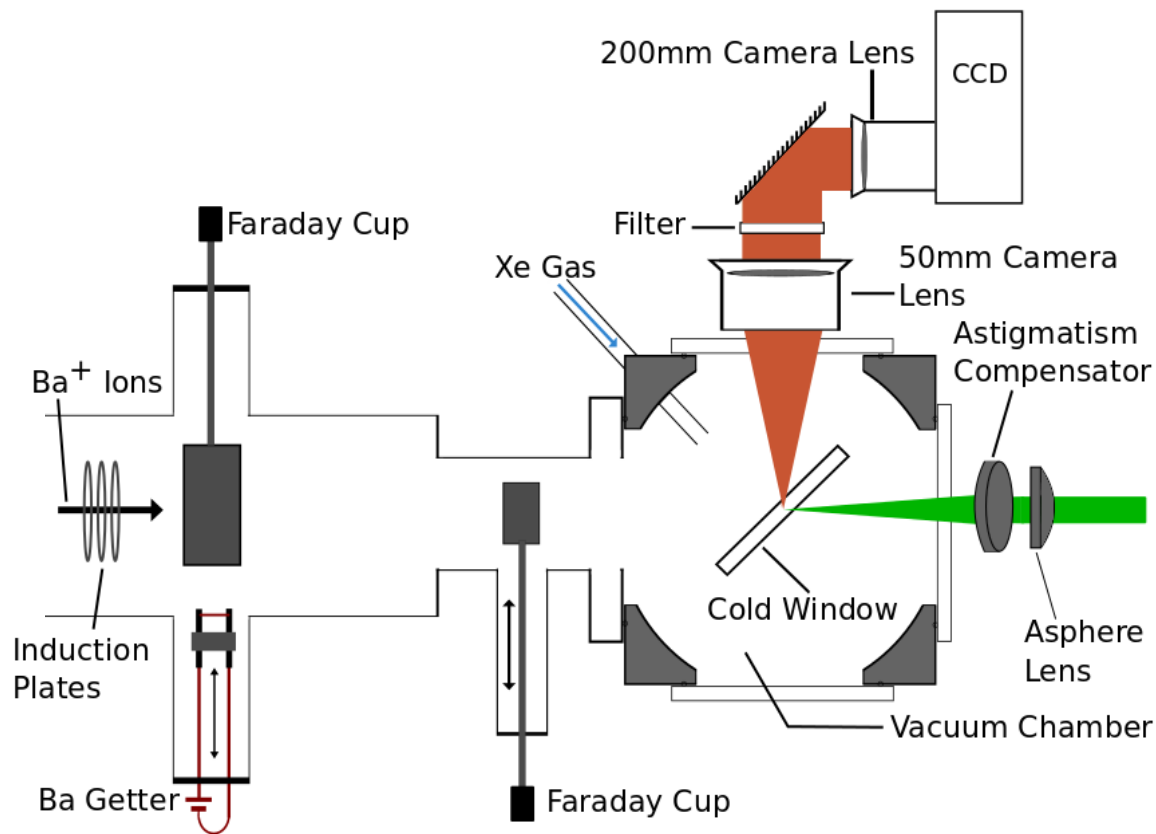
*Some neutralization
of Ba⁺ to Ba*



Deposition

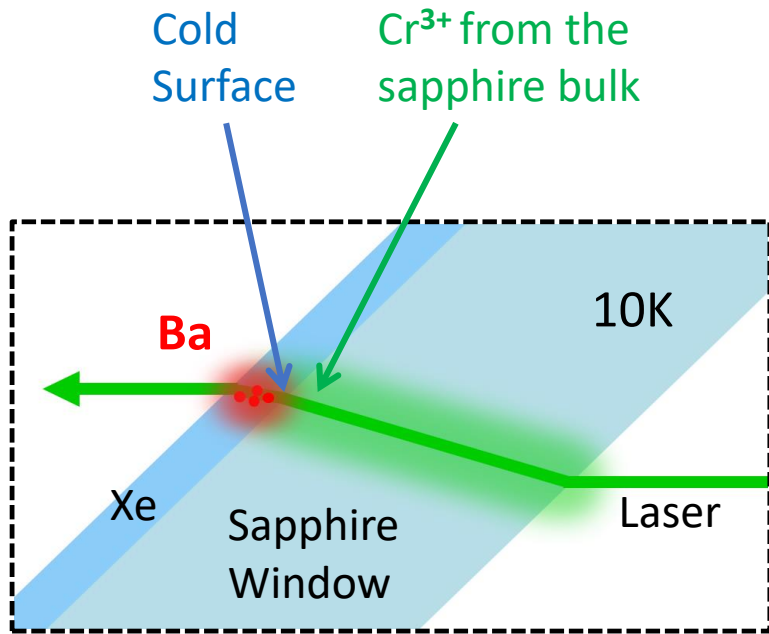
1. Cool sapphire window to 50K
2. Begin Xe gas flow for ~ 6 s
3. Pulse Ba⁺ beam onto window
4. Stop Xe gas flow after ~ 6s
5. Cool window to 10K

Observation of Ba in Solid Xe



Imaging and Background Reduction

Observed from above, there are two sources of background: surface, bulk

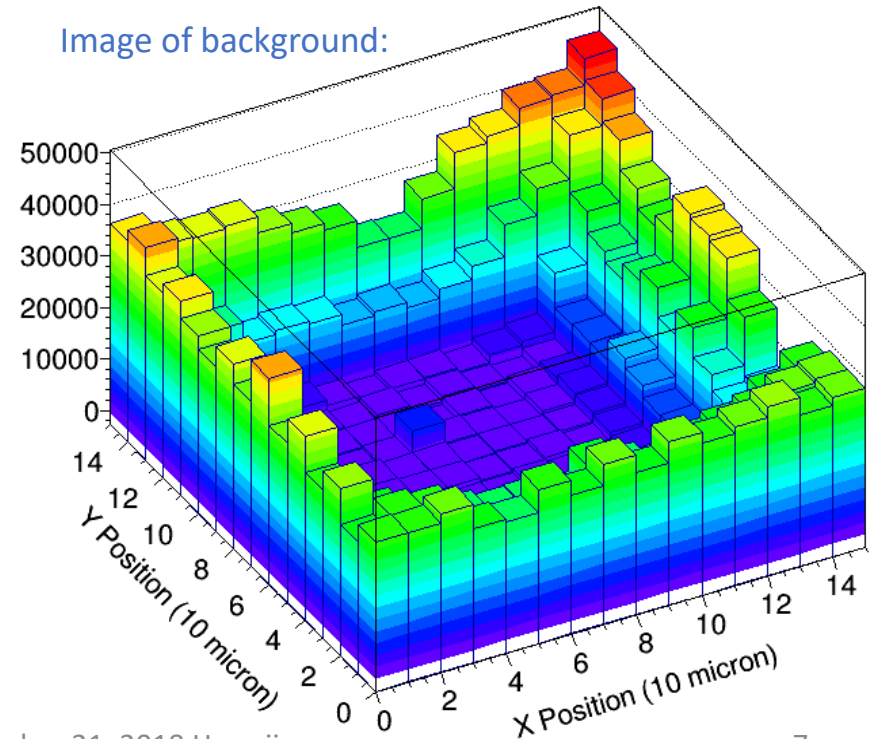


Cr³⁺ reduced with high purity windows

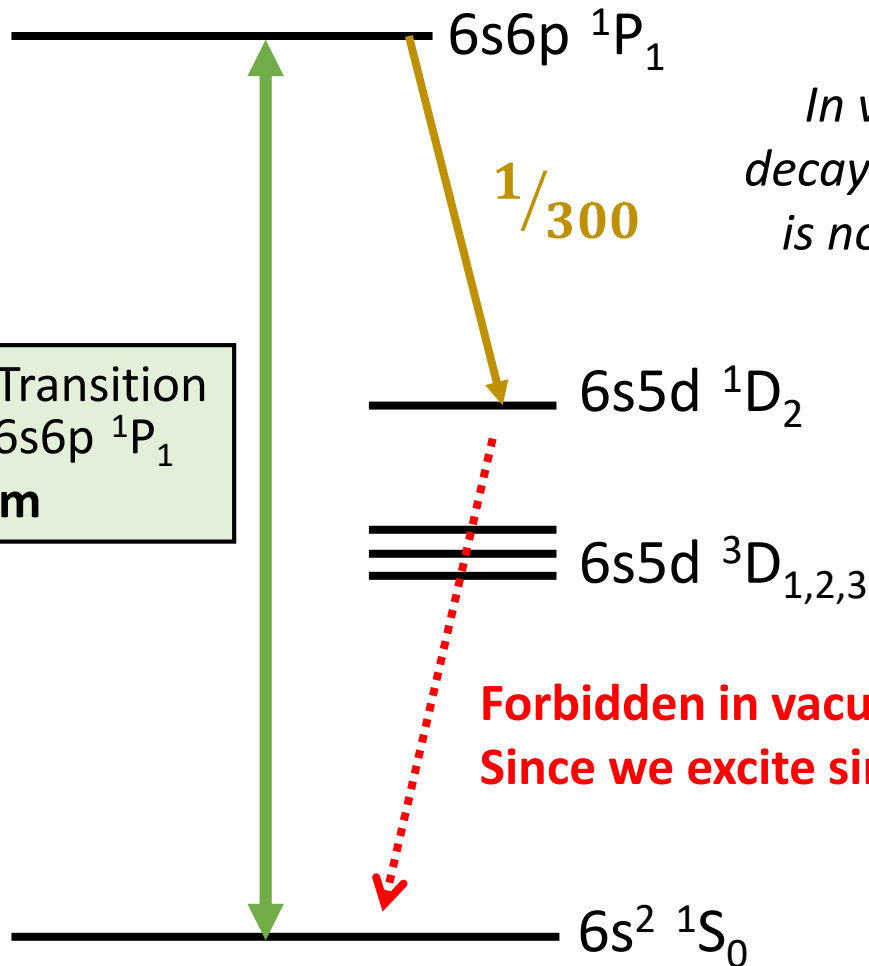
Surface background reduced via laser exposure

Raster 532 nm laser across window overnight at 100K → 30x background reduction in 90μm × 90μm area

Image of background:



Energy Levels of Ba in Vacuum



In vacuum, when the electron decays to the metastable D state, it is no longer excited by the laser.

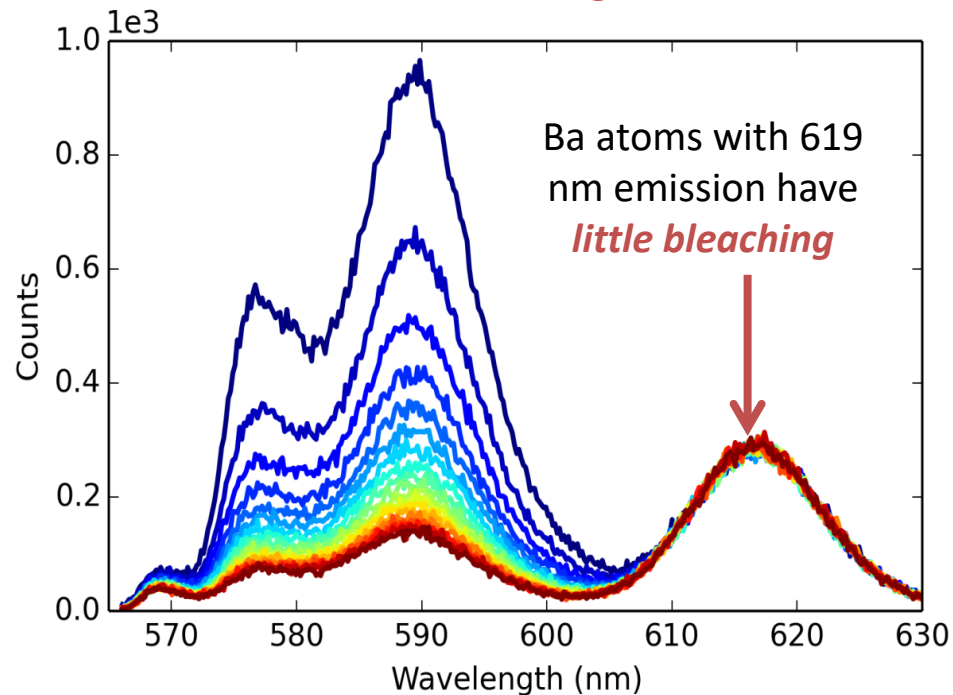
Fluorescence Transition
 $6s^2 \ ^1S_0 \longleftrightarrow 6s6p \ ^1P_1$
553.5 nm

**Forbidden in vacuum but probably not in SXe
Since we excite single atoms up to 10^7 times.**

Spectra of Ba in Solid Xe

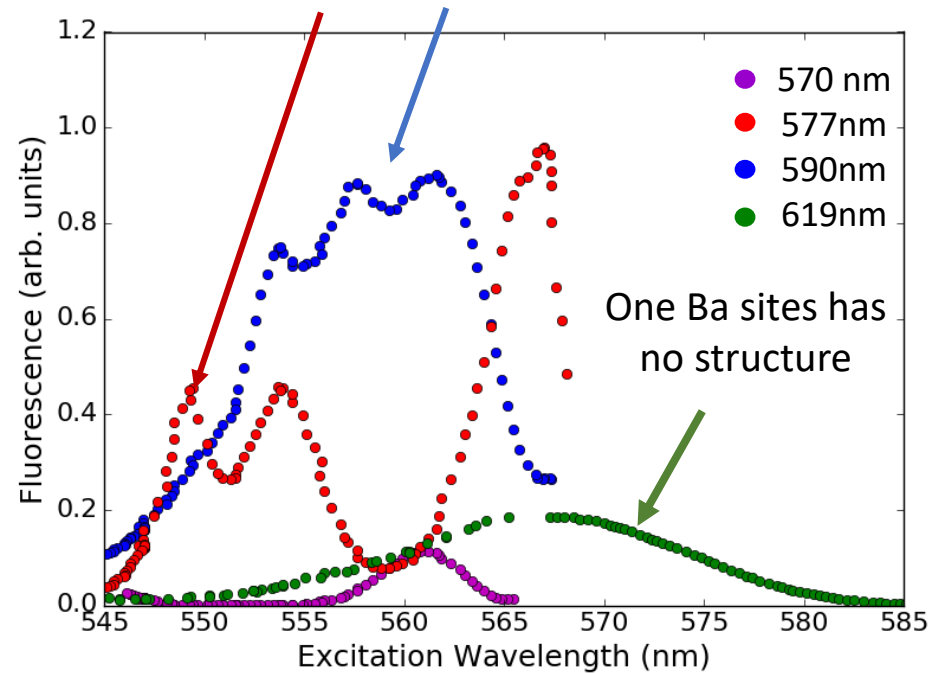
Ba Fluorescence Spectra

Three emission lines have
have more bleaching



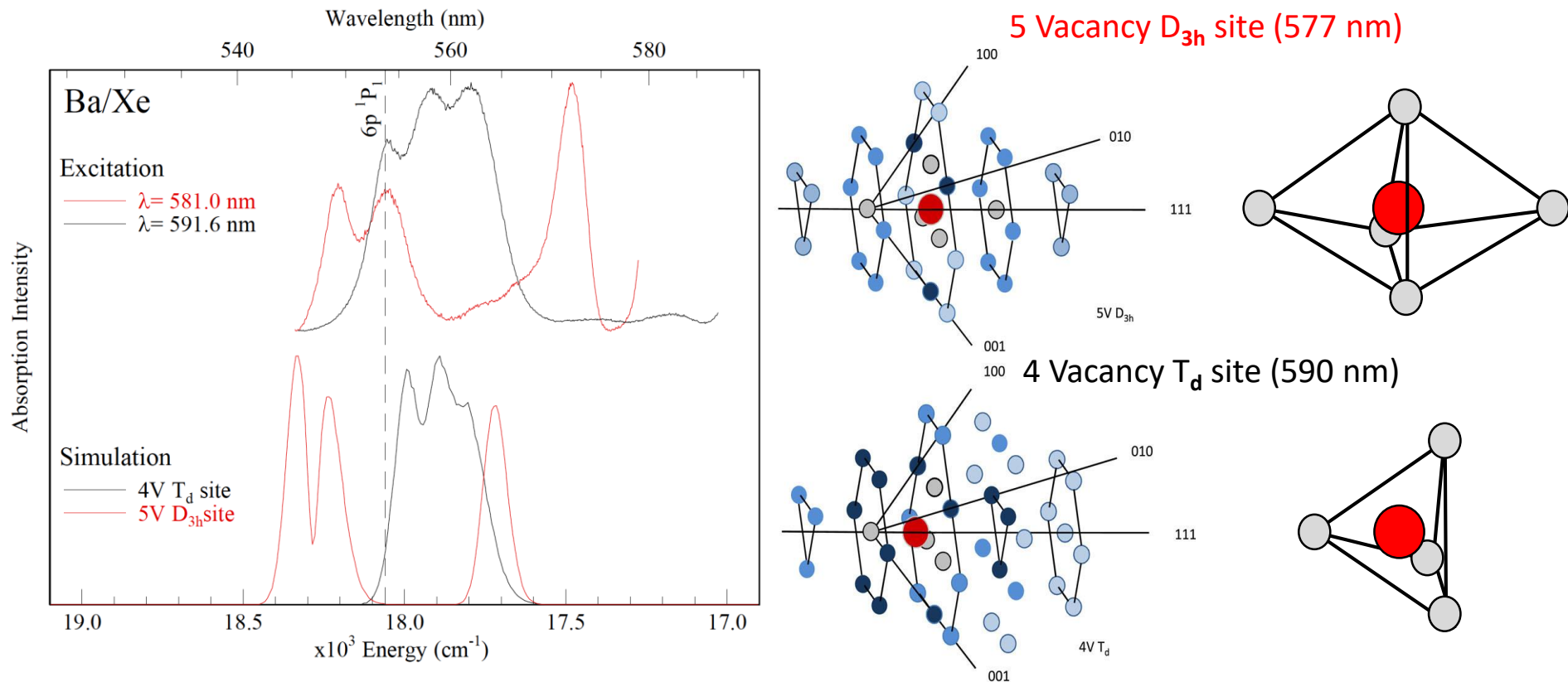
Ba Excitation Spectra

Two Ba sites have characteristic 3-peak
excitation spectrum.



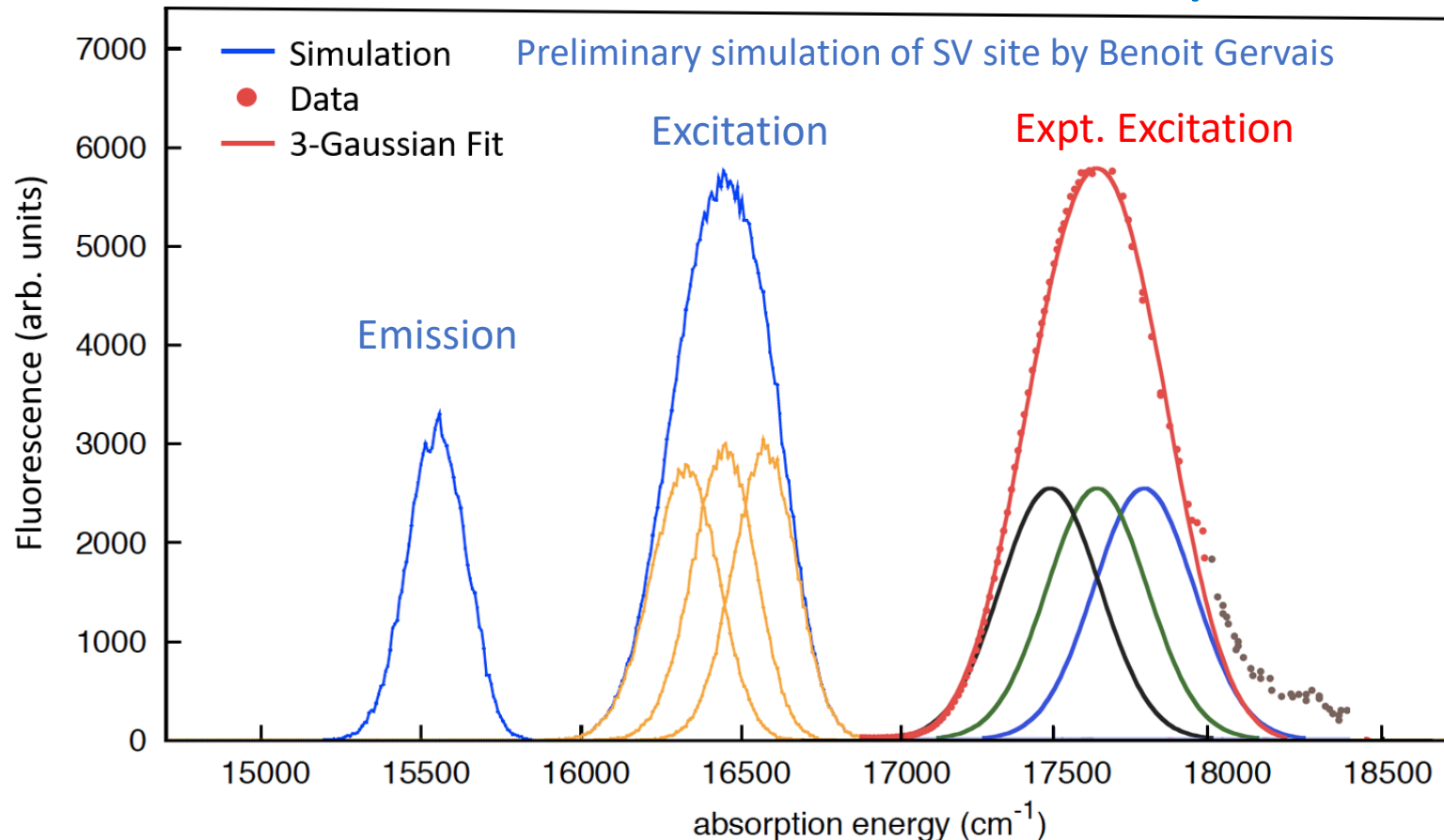
We have identified 4 distinct emission peaks, corresponding to 4 different matrix sites

Identification of matrix sites of Ba in solid Xe for two peaks



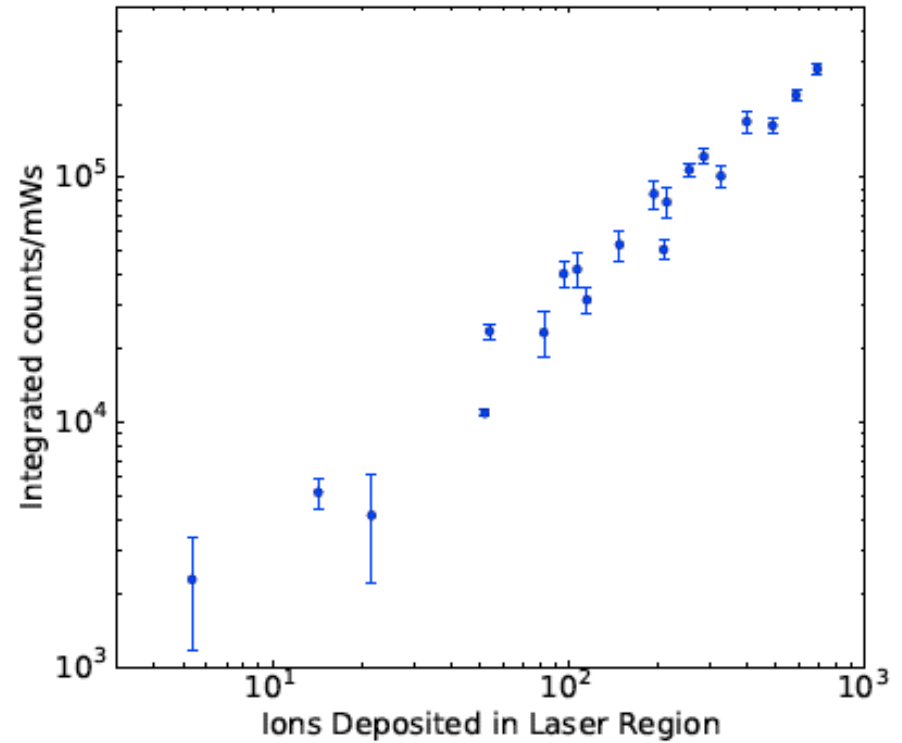
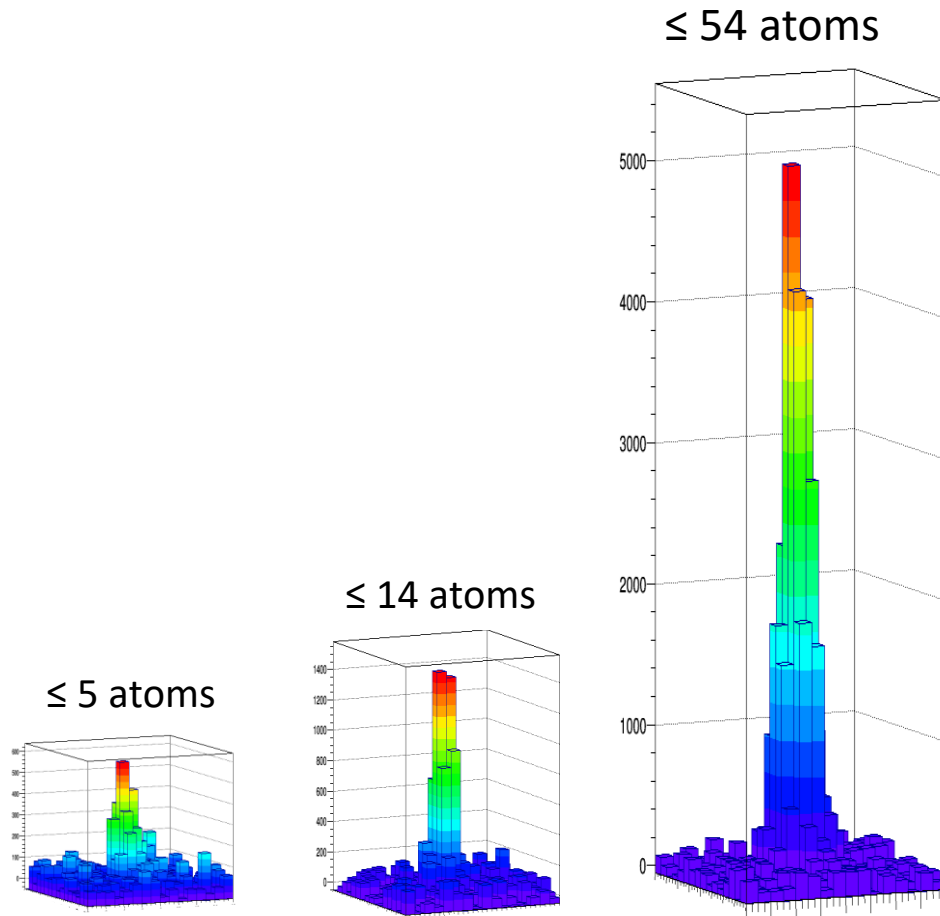
Davis, Gervais, and McCaffrey, *J. Chem. Phys.* **148**, 124308 (2018)

New: identification of 3rd matrix site of Ba in solid Xe: 619 nm peak



Single Vacancy (SV) site simulation shape qualitatively agrees with experiment
Cramped configuration is more sensitive to uncertainty in repulsive potential model

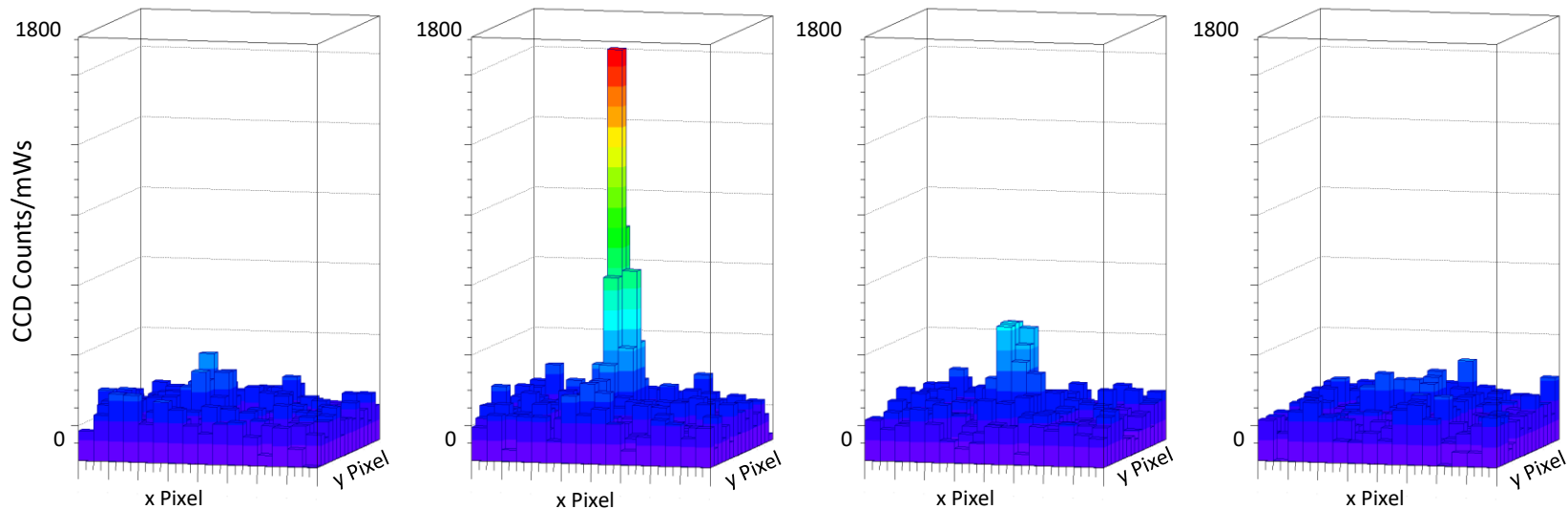
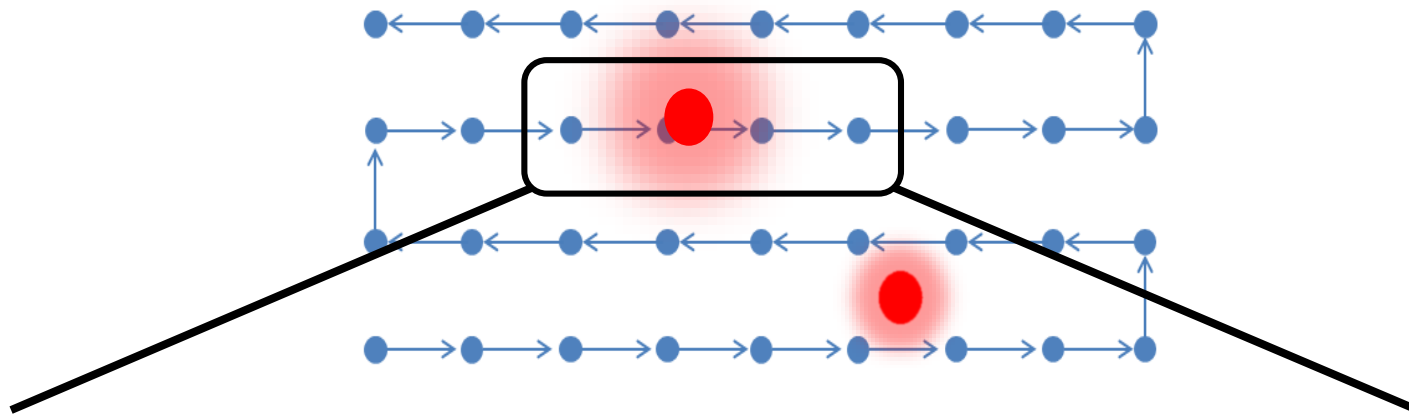
Fixed laser images of Ba in solid Xe



Fluorescence signal is linear with # of ions deposited: not Ba_n molecule!

Imaging single Ba atoms with laser scans

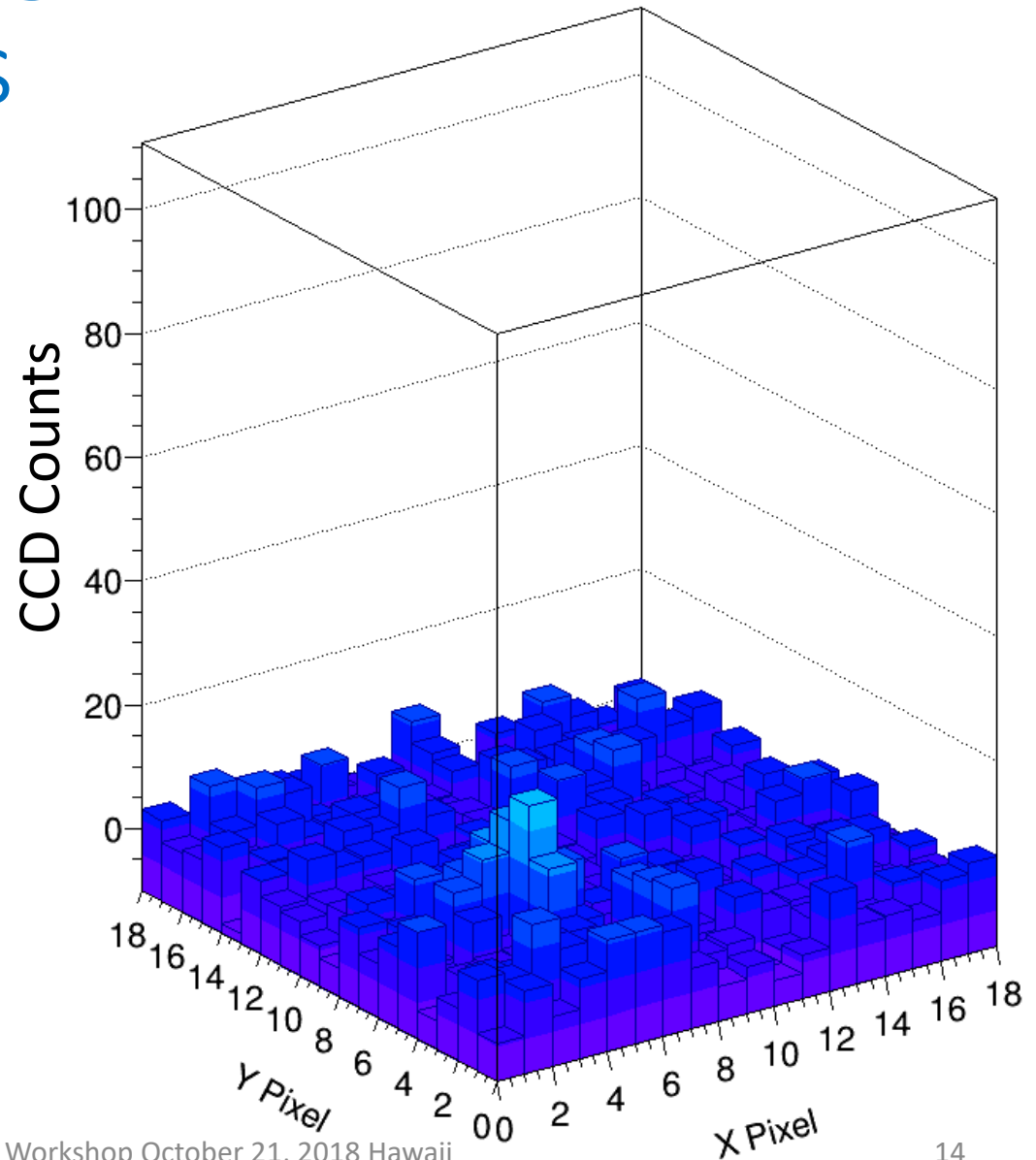
Each camera exposure is for a position in a grid:



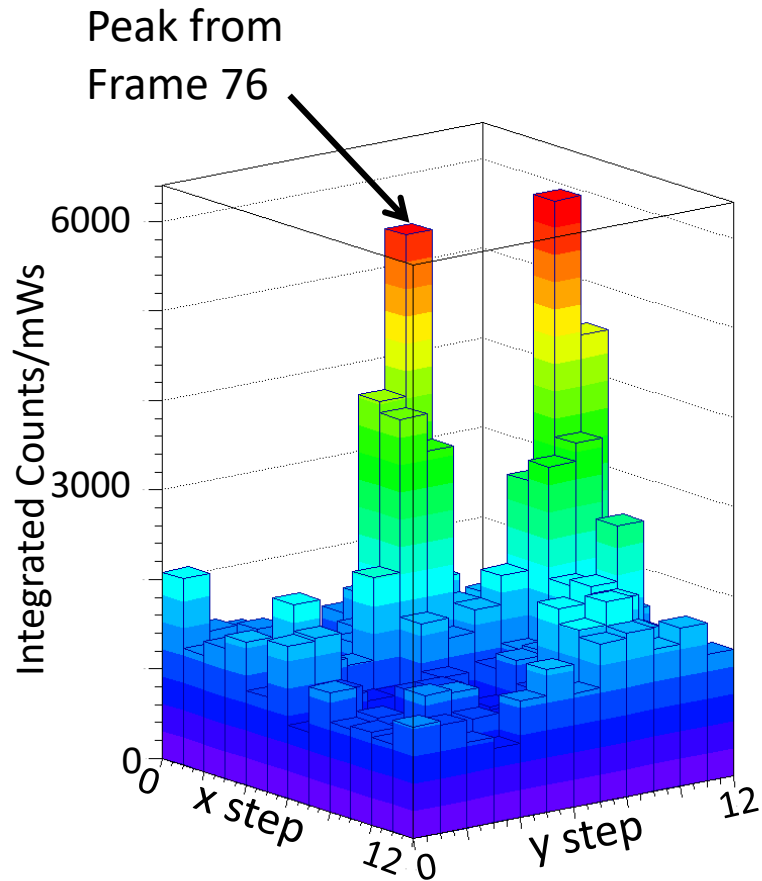
Scanning for Single Ba Atoms: raw CCD images

Scan Parameters

12 x 12 grid
x step: 4.0 μm
y step: 5.6 μm
Exposure: 3s/spot



Composite images of individual Ba atoms in solid Xe: counting Ba atoms



Making a Composite Image

Each frame is a CCD image of the laser at a grid spot

Between frames, the laser is moved to the next spot

Each frame is integrated around the laser region

Normalize by the laser exposure in mW*s

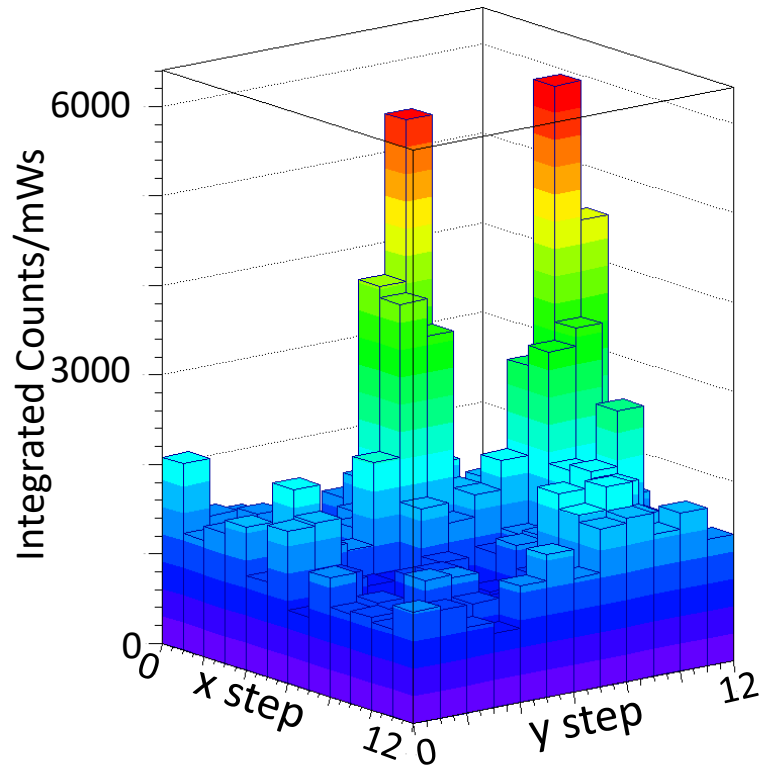
Signals plotted according to grid spot

Comment: count 2 detected Ba atoms in the scan area
 48^{+5}_{-10} Ba⁺ ions deposited in the scan area.

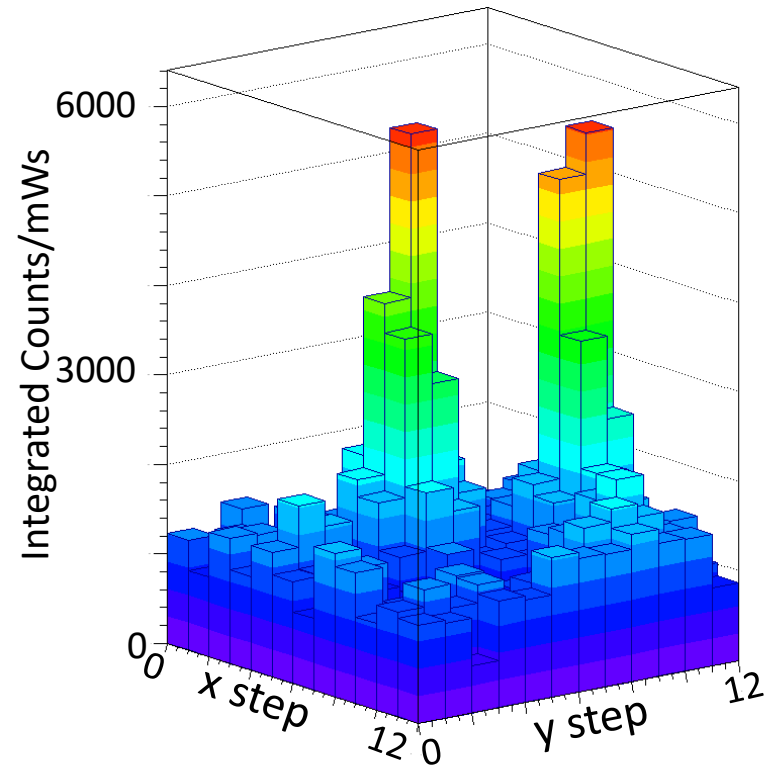
C. Chambers et al., arXiv 1806.10694, submitted to Nature

Composite images of individual Ba atoms in solid Xe: counting Ba atoms

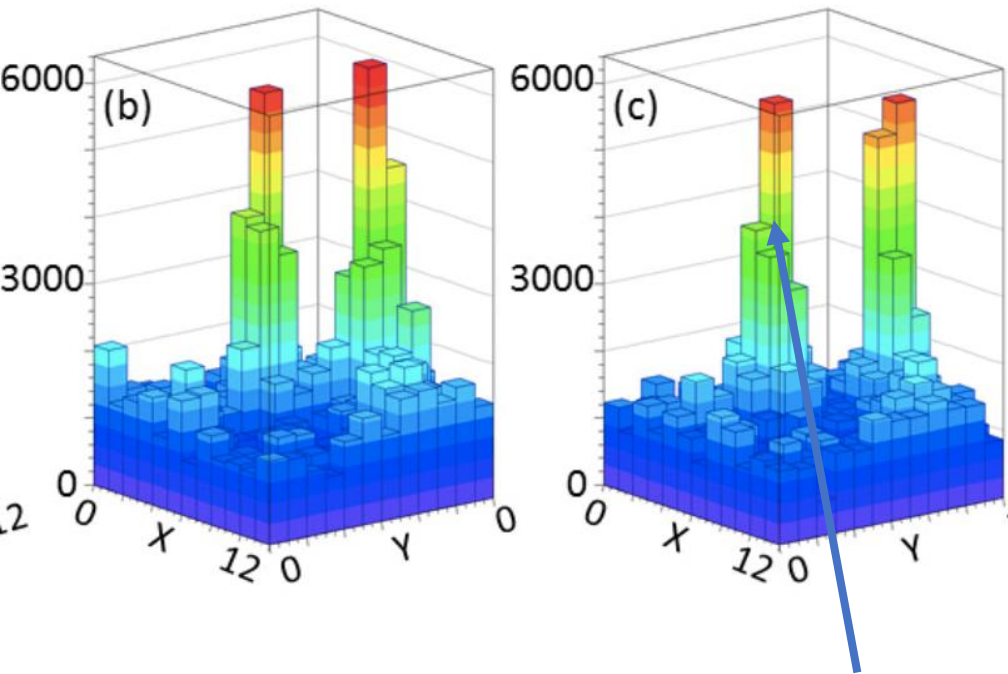
First Scan: 2 Ba atoms



Repeat Scan: 2 Ba atoms still there



Sitting on one Ba atom

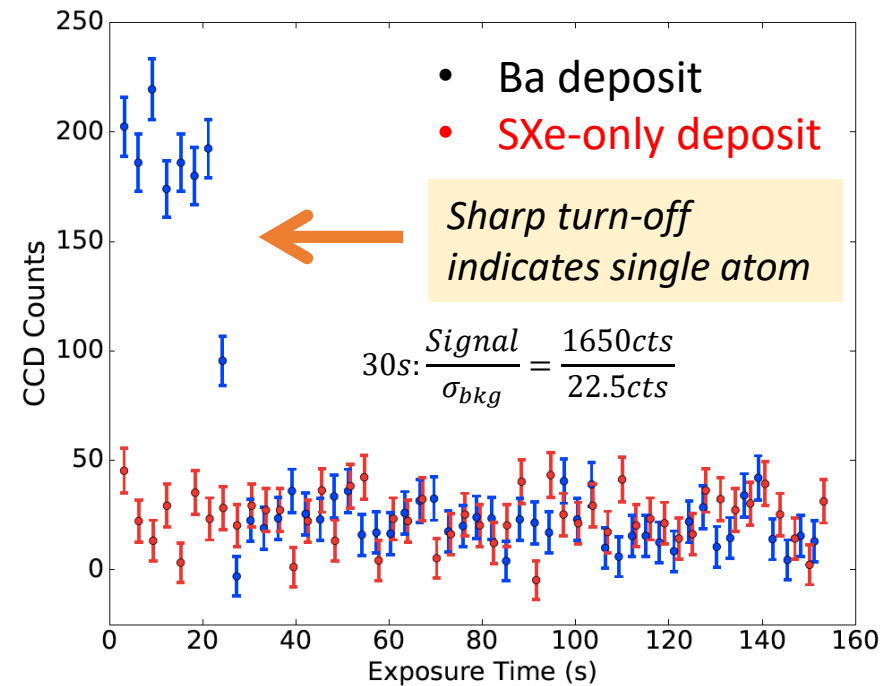


Then laser moved to near the left peak.
3s images are taken for 150 s.

Atoms emit for ~25s more, then turn off: (>300 s for other atoms)

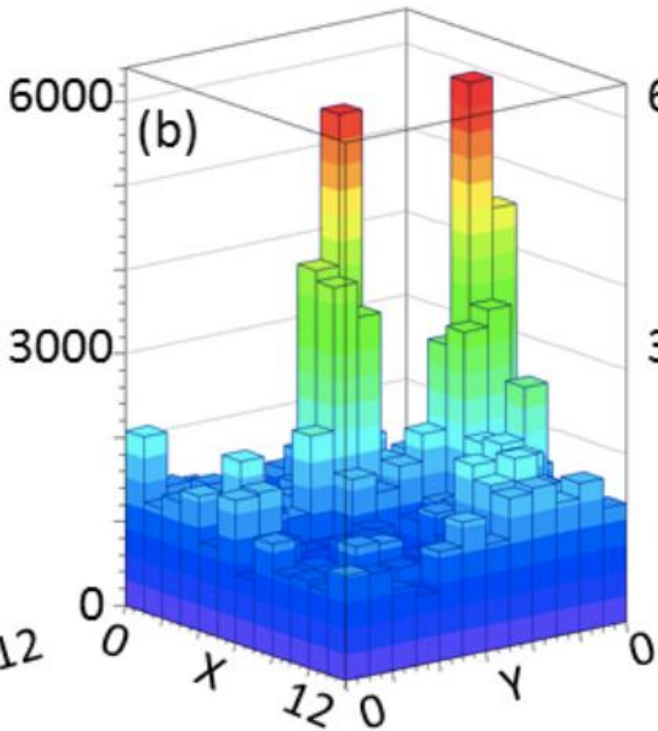
Lots of photons emitted by one Ba atom! (700,000 - $>10^7$)

Counts in laser beam region per CCD frame

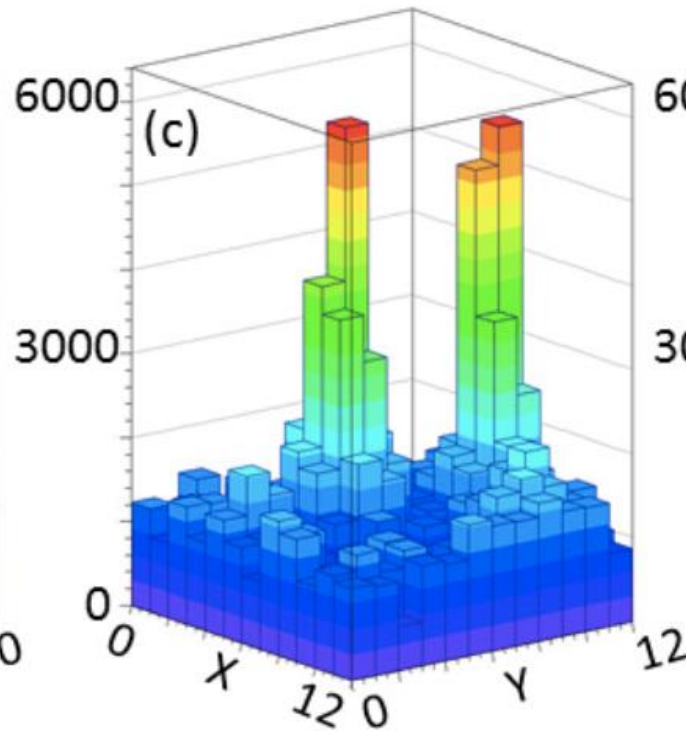


Repeat scan after sitting on one Ba atom

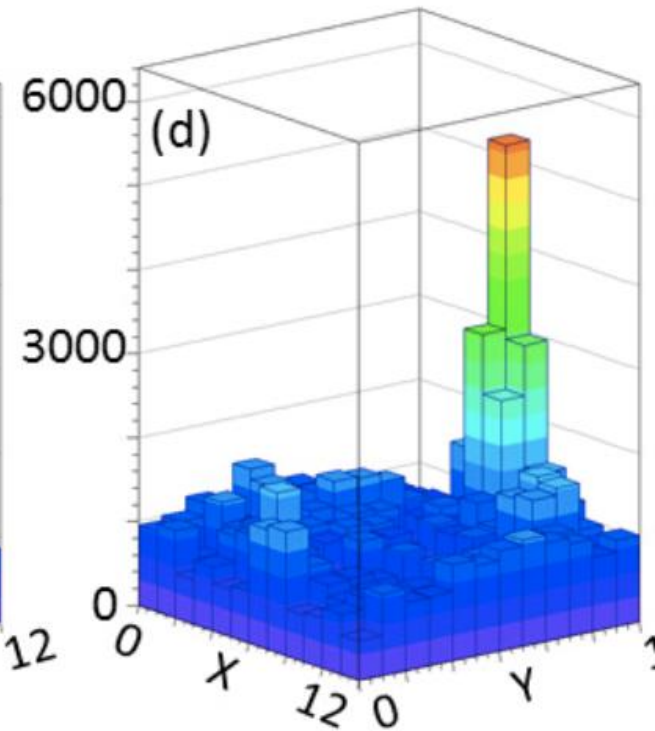
First Scan: 2 Ba



Repeat Scan: 2 Ba



Repeat Scan: after sitting near peak: one Ba is gone



Comparing scans of deposits with and without Ba pulses

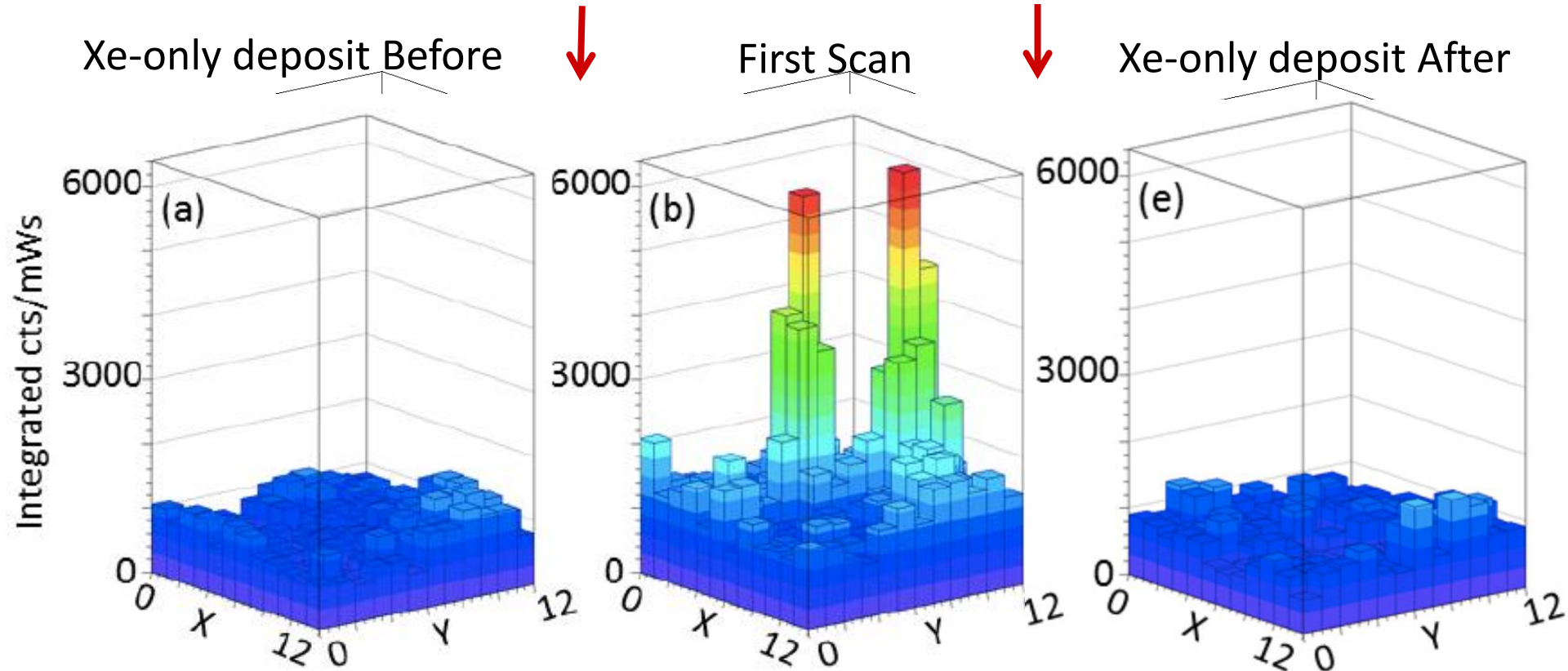
Evaporate at 100K

Evaporate at 100K

Xe-only deposit Before

First Scan

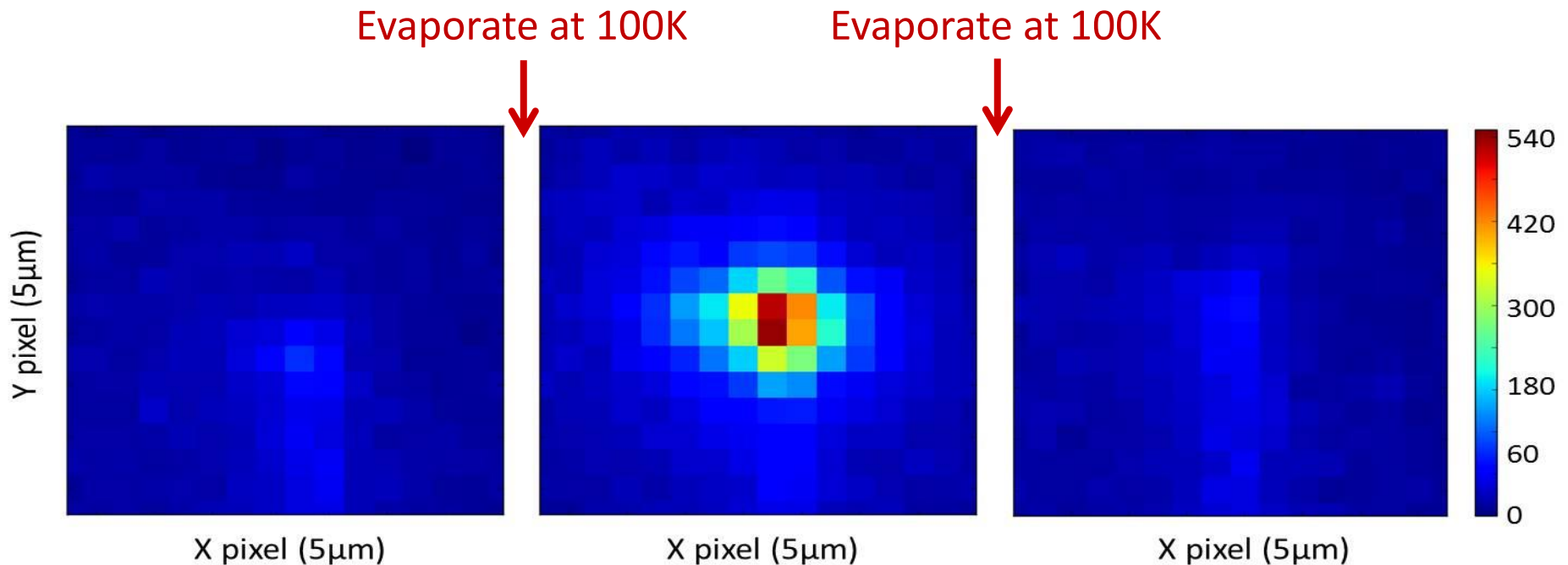
Xe-only deposit After



No Ba left behind after evaporation!

C. Chambers et al., arXiv 1806.10694, submitted to Nature

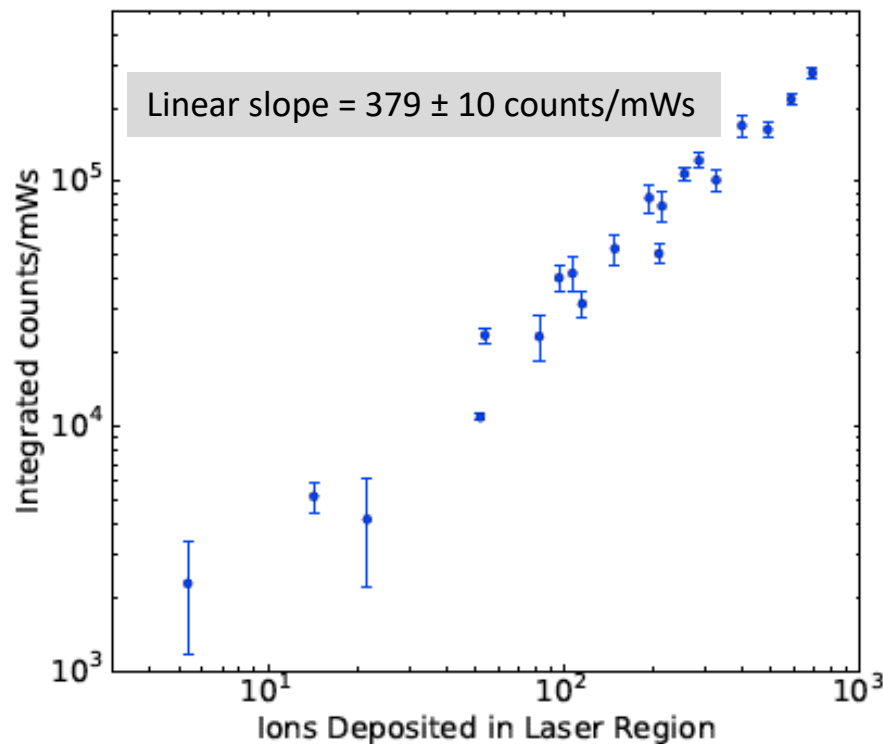
Erasing a large Ba deposit



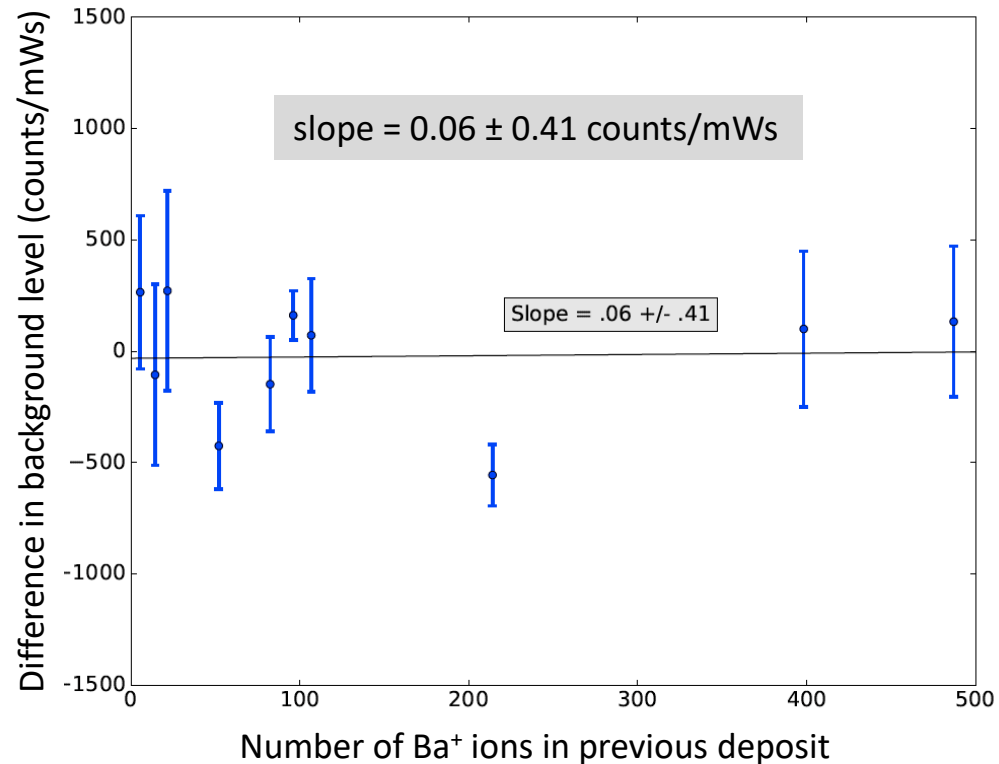
Even after a large deposit (7000 ions) all detectable Ba atoms are removed
Thus no “history effect” interfering with subsequent deposits

Quantifying erasure of Ba deposits

Ba counts/mWs



After-Before SXe only counts/mWs

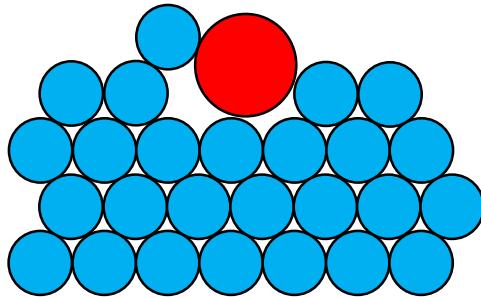


Limit of $<0.16\%$ Ba signal after evaporation
Thus no “history effect” interfering with subsequent deposits

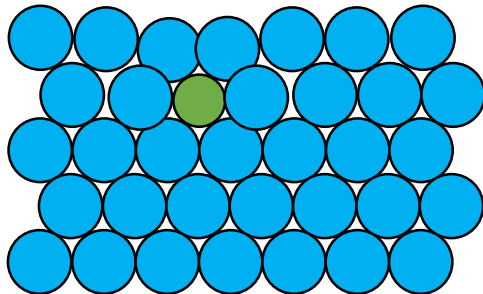
C. Chambers et al., arXiv 1806.10694, submitted to Nature

Comment on formation of matrix sites of Ba in Solid Xe

Incident Ba Atom
 $r_{\text{Ba-Xe}} = 5.5 \text{ \AA}$



Xe
 $r_{\text{Xe-Xe}} = 4.4 \text{ \AA}$



Incident Ba⁺ Ion
 $r_{\text{Ba}^+-\text{Xe}} = 3.6 \text{ \AA}$

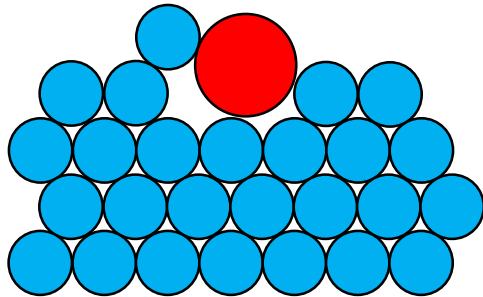
Ba atoms are too large to fit in a single vacancy (SV) site, preferring the 4- and 5-vacancy sites.

Ba implanted as an ion has a much tighter bond to Xe, thus preferring the SV site

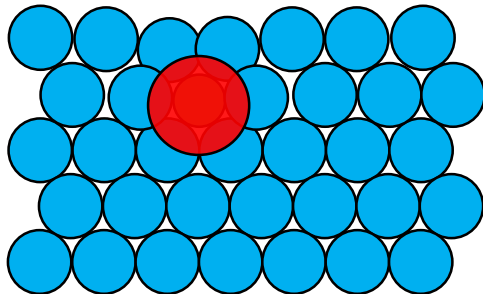
*This has already been demonstrated experimentally for Na⁺ ions in SAR:
D. C. Silverman and M. E. Fajardo,
J. Chem. Phys. 106, 8964 (1997).*

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 $r_{\text{Ba-Xe}} = 5.5 \text{ \AA}$



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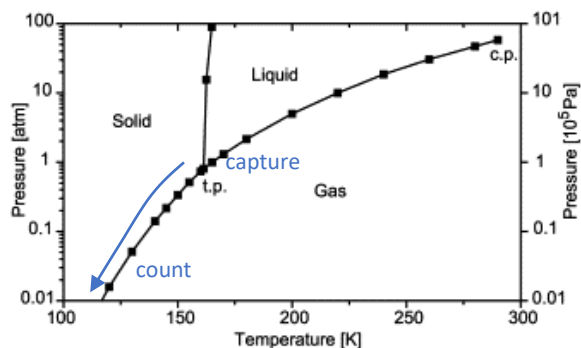
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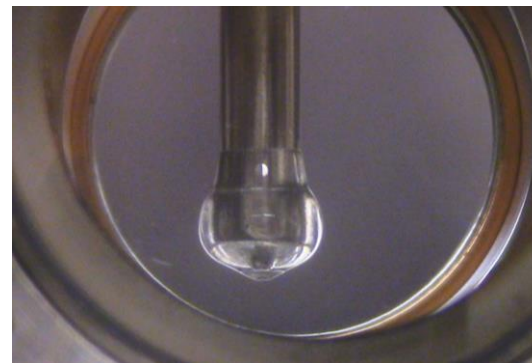
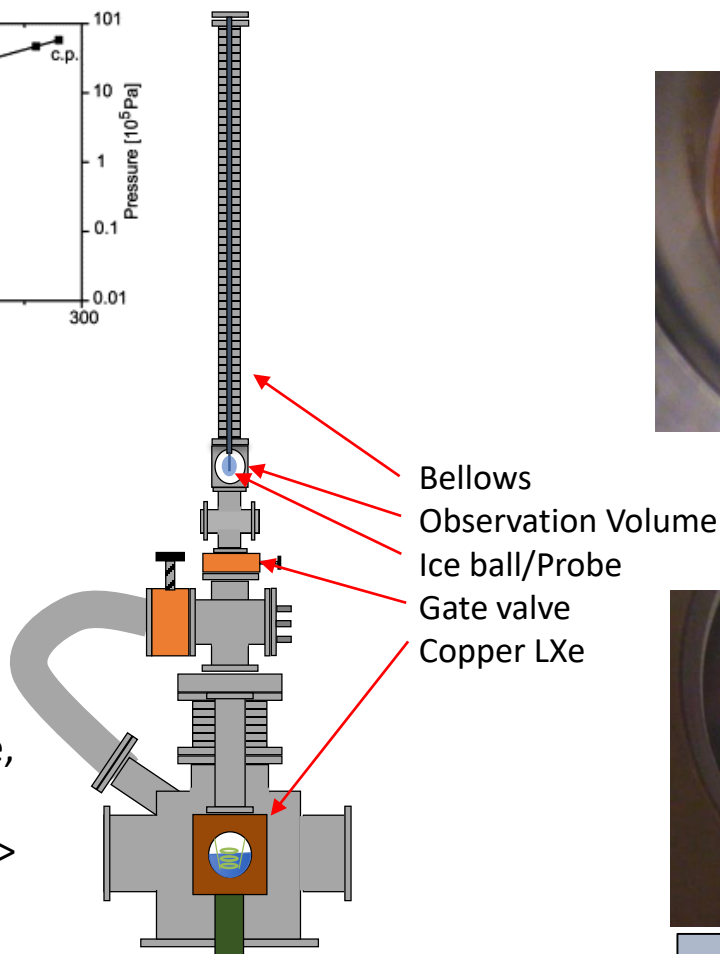
Ba implanted as an ion has a much tighter bond to Xe, thus preferring the SV site

Ba⁺ then neutralizes later to Ba, but is trapped in the cramped SV site by the Xe matrix.

Apparatus to capture Ba in SXe on a cryoprobe

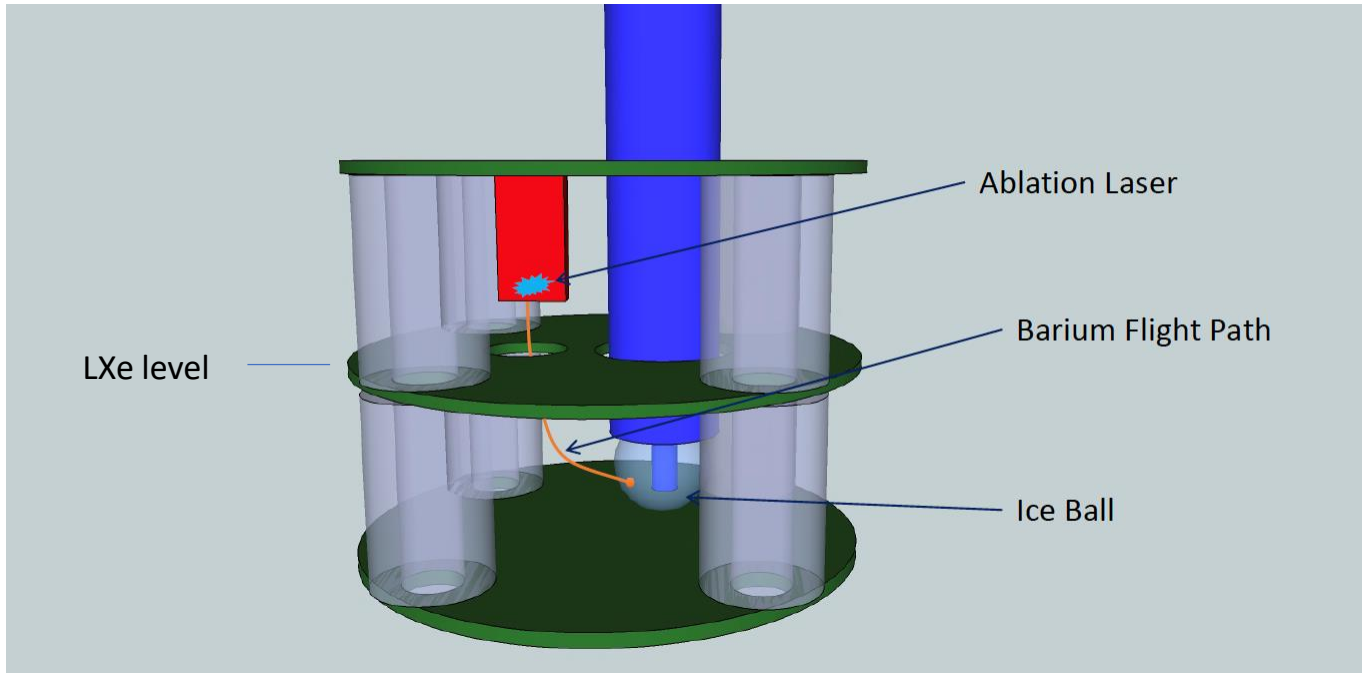


- Capture Ba in SXe at >161K.
- Raise probe to observation region.
- After close gate valve, reduce probe T and reduce Xe gas pressure, following gas-solid vapor pressure curve -> 10K.



Successful freezing from LXe and extraction to observation volume

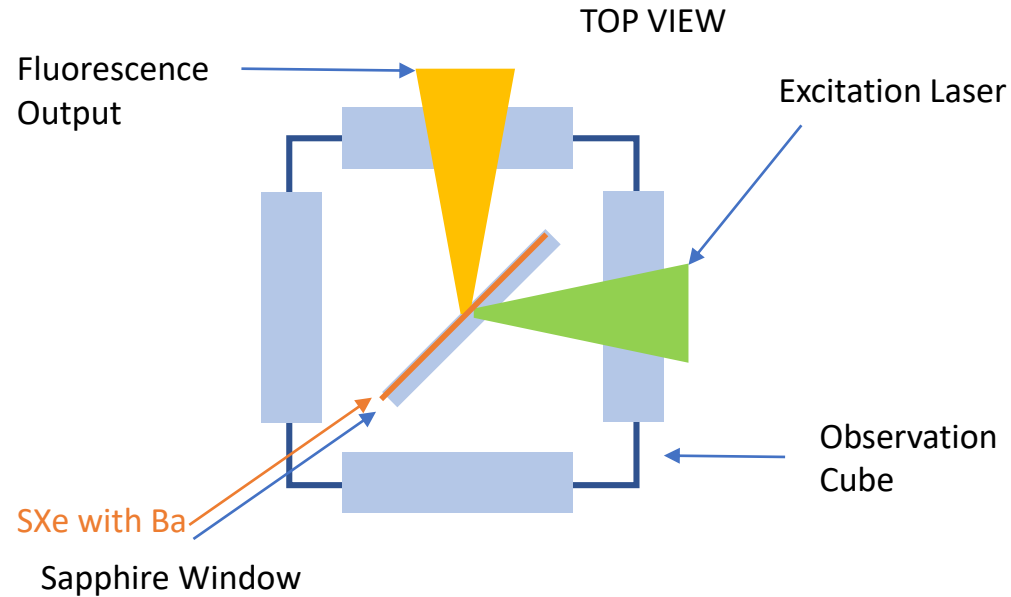
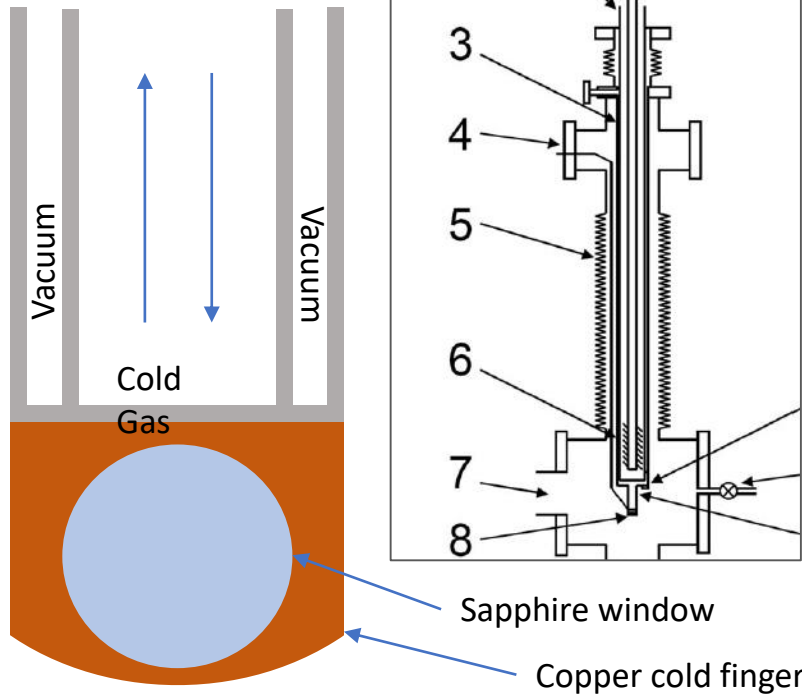
Working on implantation of Ba⁺ ions into SXe on cryoprobe



- Ba⁺ ions created by laser ablation in Xe gas
- E-field to drift ions into LXe and to cryoprobe.
- Then spectroscopy of Ba in SXe in observation chamber

A better cryoprobe for single Ba imaging

Mount sapphire window on end of cryoprobe



We are working to adapt Peter Fierlinger's helium cooled probe that included capacitive measurement of SXe thickness.

- Probe will dip into LXe and extract barium in SXe to upper observation cube
- *Similar optics of ion beam setup*

P. Fierlinger et al., Rev. Sci. Instrum. 79, 045101 (2008).

Summary

First imaging of single atoms in solid rare gas, a major step for Ba tagging in nEXO

Key features:

- Single Ba atoms can be counted with $S/\sigma \approx 70$.
- *Ba deposit is “erased” by evaporating and re-freezing a new solid Xe coating.*
- *No sensitivity to any stray Ba atoms on window surface.*
- *Ba⁺ ions preferentially go into single vacancy sites – if they neutralize after they form in SV site, they will be in the site for which we have demonstrated single Ba imaging.
(This might occur for capture from LXe!)*

nEXO Collaboration



University of Alabama

University of Bern, Switzerland

Brookhaven National Laboratory

University of California, Irvine

California Institute of Technology

Carleton University, Canada

Colorado State University

Drexel University

Duke University

Friedrich-Alexander-University Erlangen, Germany

IBS Center for Underground Physics, Daejeon, South Korea

IHEP Beijing, People's Republic of China

IME Beijing, People's Republic of China

ITEP Moscow, Russia

University of Illinois, Urbana-Champaign

Indiana University

Laurentian University, Canada

Lawrence Livermore National Laboratory

University of Massachusetts

McGill University, Canada

University of North Carolina, Wilmington

Oak Ridge National Laboratory

Pacific Northwest National Laboratory

Rensselaer Polytechnic Institute

Université de Sherbrooke, Canada

SLAC National Accelerator Laboratory

University of South Dakota

Stanford University

Stony Brook University

Technical University of Munich, Germany

TRIUMF, Vancouver, Canada

Yale University